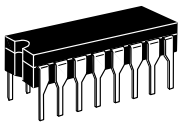
MC14415

Quad Precision Timer/Driver

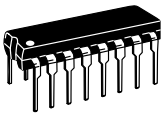
MC14415 quad timer/driver is constructed with complementary MOS enhancement mode devices. The output pulse width of each digital timer is a function of the input clock frequency. Once the proper input sequence is detected the output buffer is set (turned on), and after 100 clock pulses are counted, the output buffer is reset (turned off).

The MC14415 was designed specifically for application in high speed line printers to provide the critical timing of the hammer drivers, but may be used in many applications requiring precision pulse widths.

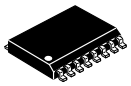
- Four Precision Digital Time Delays
- Schmitt Trigger Clock Conditioning
- NPN Bipolar Output Drivers
- Timing Disable Capability Using Inhibit Output
- Positive or Negative Edge Strobing on the Inputs
- Synchronous Polynomial Counters Used for Delay Counting



L SUFFIX
CERAMIC
CASE 620



P SUFFIX
PLASTIC
CASE 648



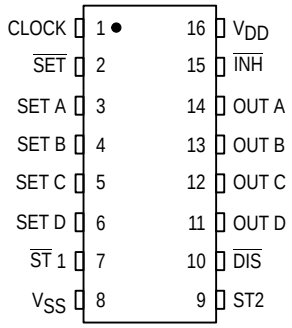
DW SUFFIX
SOIC
CASE 751G

ORDERING INFORMATION

MC14415FP (3.0 V–18 V)	Plastic
MC14415VP (3.0 V–6.0 V)	Plastic
MC14415FL (3.0 V–18 V)	Ceramic
MC14415VL (3.0 V–6.0 V)	Ceramic
MC14415DW (3.0 V–18 V)	SOIC

T_A = – 55° to 125°C for all packages.

PIN ASSIGNMENT

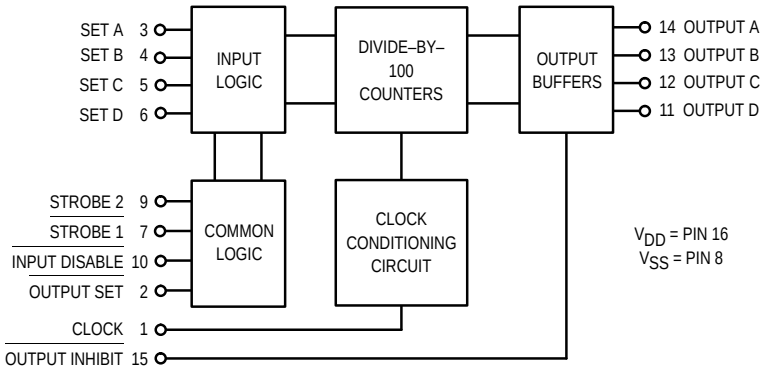


MAXIMUM RATINGS* (Voltages Referenced to V_{SS})

Rating	Symbol	Value	Unit
DC Supply Voltage MC14415FL, FP,DW MC14415VL, VP	V_{DD}	– 0.5 to + 18.0 – 0.5 to + 6.0	V
Input or Output Voltage (DC or Transient)	V_{in}, V_{out}	– 0.5 to V_{DD} + 0.5	V
Input Current (DC or Transient), per Pin	I_{in}	± 10	mA
Output Current (DC or Transient), per Pin	I_{out}	± 20	mA
Power Dissipation, per Package†	P_D	500	mW
Storage Temperature	T_{stg}	– 65 to + 150	°C
Lead Temperature (8–Second Soldering)	T_L	260	°C

* Maximum Ratings are those values beyond which damage to the device may occur.
†Temperature Derating:
Plastic "P and D/DW" Packages: – 7.0 mW/°C From 65°C To 125°C
Ceramic "L" Packages: – 12 mW/°C From 100°C To 125°C

BLOCK DIAGRAM



ELECTRICAL CHARACTERISTICS (Voltages Referenced to V_{SS})

Characteristic	Symbol	V_{DD} Vdc	– 55°C Min	– 55°C Max	25°C Min	25°C Typ #	25°C Max	125°C Min	125°C Max	Unit
Output Voltage "0" Level (No Load)	V_{OL}	5.0	—	0.01	—	0	0.01	—	0.05	Vdc
		10	—	0.01	—	0	0.01	—	0.05	
		15	—	—	—	—	—	—	—	
"1" Level	V_{OH}	5.0	—	—	3.0	4.14	—	—	—	Vdc
		10	—	—	8.0	9.09	—	—	—	
		15	—	—	—	14.12	—	—	—	
Noise Immunity	V_{NL}									Vdc
($\Delta V_{out} \leq 1.5$ Vdc)		5.0	1.5	—	1.5	2.25	—	1.4	—	
($\Delta V_{out} \leq 3.0$ Vdc)		10	3.0	—	3.0	4.50	—	2.9	—	
($\Delta V_{out} \leq 4.5$ Vdc)		15	—	—	—	6.75	—	—	—	
($\Delta V_{out} \leq 1.5$ Vdc)	V_{NH}	5.0	1.4	—	1.5	2.25	—	1.5	—	Vdc
($\Delta V_{out} \leq 3.0$ Vdc)		10	2.9	—	3.0	4.50	—	3.0	—	
($\Delta V_{out} \leq 4.5$ Vdc)		15	—	—	—	6.75	—	—	—	
Output Drive Voltage (NPN Driver)	V_{OH}									Vdc
(I_{OH} = 0 mA) Source		5.0	—	—	3.0	4.14	—	—	—	
(I_{OH} = 5.0 mA)			—	—	2.7	3.44	—	—	—	
(I_{OH} = 10 mA)			—	—	2.5	3.30	—	—	—	
(I_{OH} = 15 mA)			—	—	2.2	3.08	—	—	—	
(I_{OH} = 0 mA)		10	—	—	8.0	9.09	—	—	—	Vdc
(I_{OH} = 5.0 mA)			—	—	7.7	8.45	—	—	—	
(I_{OH} = 10 mA)			—	—	7.5	8.30	—	—	—	
(I_{OH} = 15 mA)			—	—	7.1	8.14	—	—	—	
(I_{OH} = 0 mA)		15	—	—	—	14.12	—	—	—	Vdc
(I_{OH} = 5.0 mA)			—	—	—	13.81	—	—	—	
(I_{OH} = 10 mA)			—	—	—	13.70	—	—	—	
(I_{OH} = 15 mA)			—	—	—	13.61	—	—	—	
Output Drive Current	I_{OL}									mAdc
(V_{OL} = 0.4 Vdc) Sink		5.0	0.23	—	0.2	0.78	—	0.16	—	
(V_{OL} = 0.5 Vdc)		10	0.60	—	0.5	2.0	—	0.40	—	
(V_{OL} = 1.5 Vdc)		15	—	—	—	7.8	—	—	—	
Input Leakage Current	I_{in}	15	—	± 0.3	—	±0.00001	± 0.3	—	± 1.0	µAdc
Input Capacitance (V_{in} = 0)	C_{in}	—	—	—	—	5.0	—	—	—	pF
Quiescent Dissipation	P_Q	5.0	—	0.25	—	0.00005	0.25	—	3.5	mW
		10	—	1.0	—	0.00022	1.0	—	14	
		15	—	—	—	0.00050	—	—	—	
Power Dissipation** (Dynamic plus Quiescent) (C_L = 15 pF)	P_D	5.0	P_D (56 mW/MHz) f + P_Q							mW
		10	P_D (225 mW/MHz) f + P_Q							
		15	P_D (510 mW/MHz) f + P_Q							

#Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.
** The formulas given are for the typical characteristics only.

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation, V_{in} and V_{out} should be constrained to the range $V_{SS} \leq (V_{in}$ or $V_{out}) \leq V_{DD}$.

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either V_{SS} or V_{DD}). Unused outputs must be left open.

SWITCHING CHARACTERISTICS* (C_L = 15 pF, T_A = 25°C)

Characteristic	Symbol	V_{DD} Vdc	Min	Typ #	Max	Unit
Output Rise Time	t_{TLH}					ns
t_{TLH} = (2.0 ns/pF) C_L + 10 ns		5.0	—	40	85	
t_{TLH} = (1.25 ns/pF) C_L + 6 ns		10	—	25	60	
t_{TLH} = (1.10 ns/pF) C_L + 3 ns		15	—	20	—	
Output Fall Time	t_{THL}					ns
t_{THL} = (1.5 ns/pF) C_L + 47 ns		5.0	—	70	150	
t_{THL} = (0.75 ns/pF) C_L + 24 ns		10	—	35	80	
t_{THL} = (0.55 ns/pF) C_L + 17 ns		15	—	25	—	
Turn–Off Delay Time	t_{PLH}					ns
t_{PLH} = (2.7 ns/pF) C_L + 560 ns		5.0	—	600	1200	
t_{PLH} = (1.2 ns/pF) C_L + 282 ns		10	—	300	600	
t_{PLH} = (0.91 ns/pF) C_L + 286 ns		15	—	150	—	
Turn–On Delay Time	t_{PHL}					ns
t_{PHL} = (2.4 ns/pF) C_L + 564 ns		5.0	—	600	1200	
t_{PHL} = (1.0 ns/pF) C_L + 285 ns		10	—	300	600	
t_{PHL} = (0.75 ns/pF) C_L + 289 ns		15	—	150	—	
Turn–On Delay Time ($\overline{\text{Inhibit}}$ to Output)	t_{PHL}					ns
		5.0	—	300	550	
		10	—	225	425	
		15	—	110	—	
Turn–Off Delay Time ($\overline{\text{Inhibit}}$ to Output)	t_{PLH}					ns
		5.0	—	300	550	
		10	—	225	425	
		15	—	110	—	
Input Pulse Coincidence (Figure 3)	PC_{min}					ns
		5.0	500	450	—	
		10	450	350	—	
		15	—	—	—	
Input Pulse Width (Figure 1)	t_{WH}					ns
		5.0	500	450	—	
		10	450	350	—	
		15	—	—	—	
Input Clock Frequency	f_{cl}					MHz
		5.0	—	0.7	—	
		10	—	1.0	—	
		15	—	1.5	—	
Clock Input Rise and Fall Times (Figure 1)	t_{TLH}, t_{THL}	5.0	—	—	15	µs
		10	—	—	5.0	
		15	—	—	4.0	

* The formulas given are for the typical characteristics only at 25°C.
#Data labelled “Typ” is not to be used for design purposes but is intended as an indication of the IC’s potential performance.

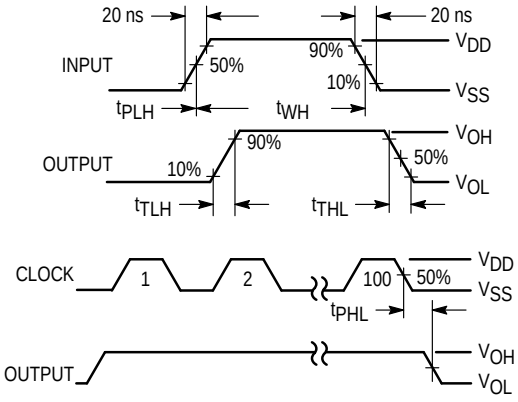
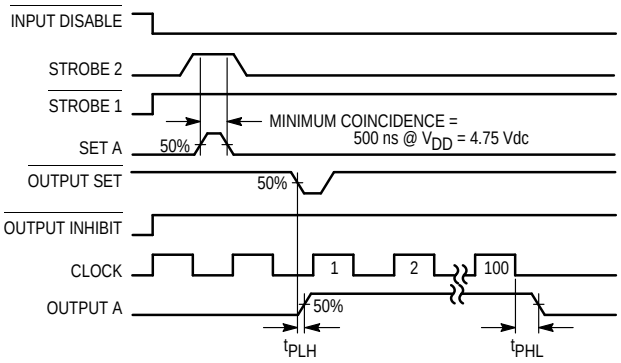
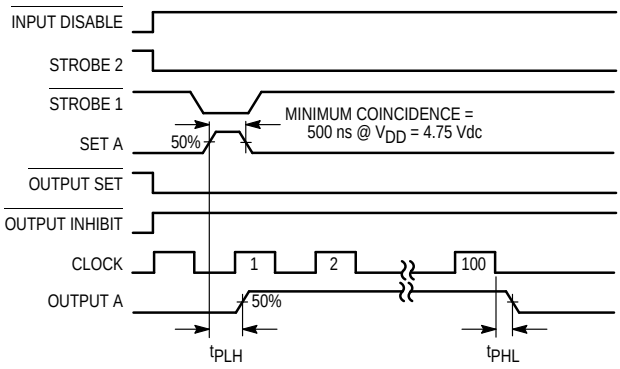


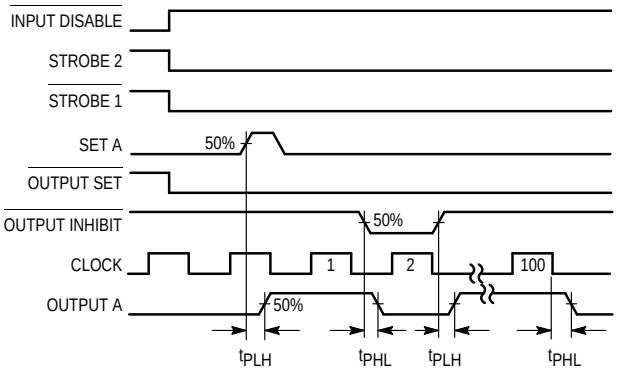
Figure 1. Switching Characteristics — Waveform Relationships



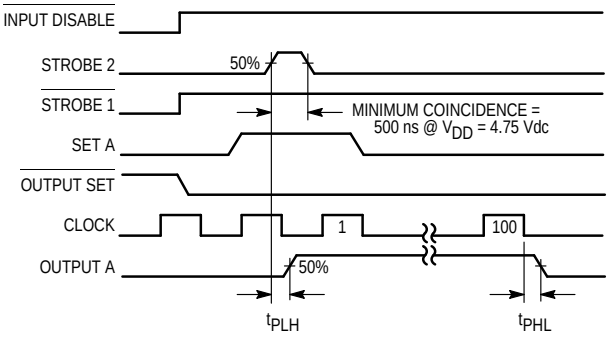
Mode 1: $\overline{\text{OUTPUT SET}}$ Initiates Time Delay



Mode 2: Set A Initiates Time Delay



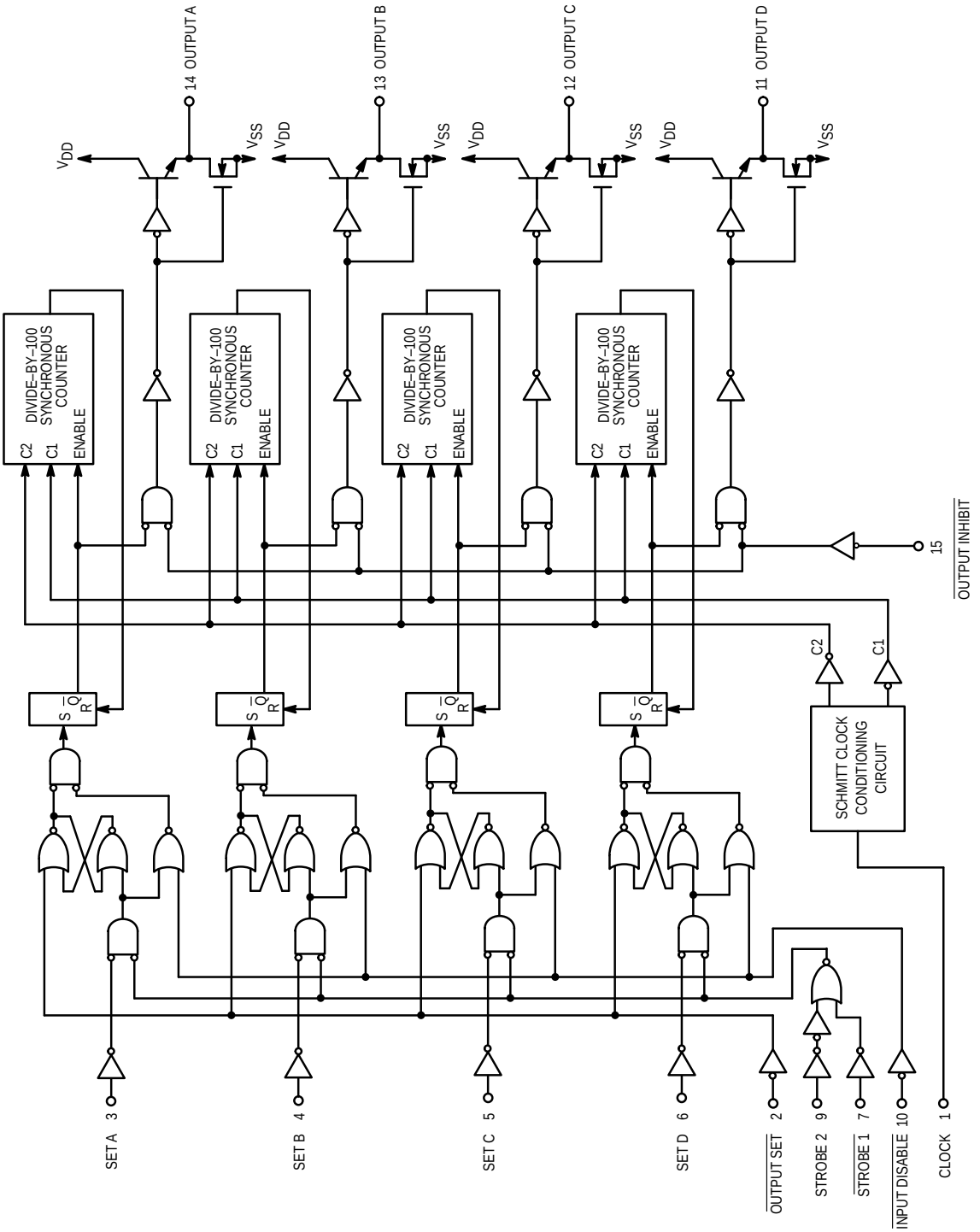
Mode 3: $\overline{\text{OUTPUT INHIBIT}}$ Disables Time Delay



Mode 4: Positive–Edge Strobe (ST2) Initiates Time Delay

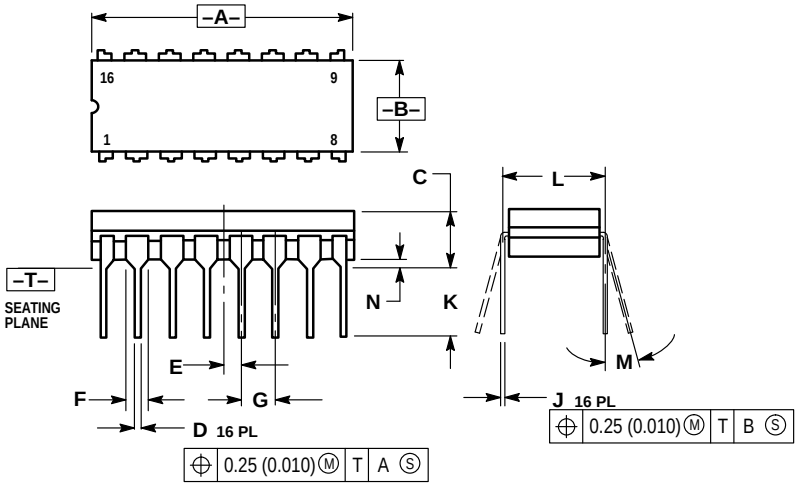
Figure 2. Typical Operation Modes and Functional Timing Diagram

LOGIC DIAGRAM



OUTLINE DIMENSIONS

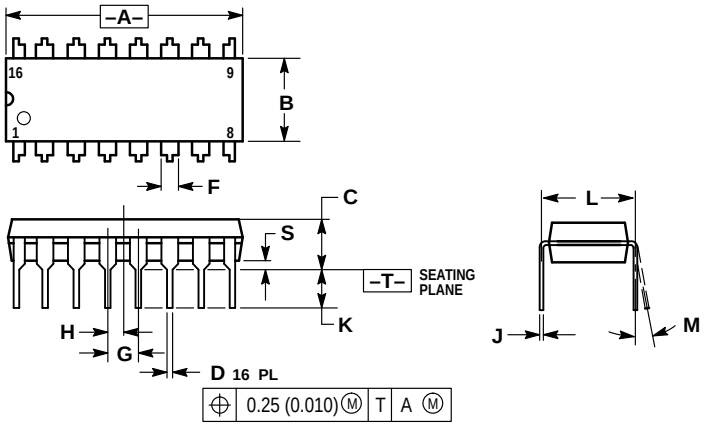
L SUFFIX
CERAMIC DIP PACKAGE
CASE 620–10
ISSUE V



NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. DIMENSION L TO CENTER OF LEAD WHEN FORMED PARALLEL.
4. DIMENSION F MAY NARROW TO 0.76 (0.030) WHERE THE LEAD ENTERS THE CERAMIC BODY.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
A	0.750	0.785	19.05	19.93
B	0.240	0.295	6.10	7.49
C	—	0.200	—	5.08
D	0.015	0.020	0.39	0.50
E	0.050 BSC		1.27 BSC	
F	0.055	0.065	1.40	1.65
G	0.100 BSC		2.54 BSC	
H	0.008	0.015	0.21	0.38
K	0.125	0.170	3.18	4.31
L	0.300 BSC		7.62 BSC	
M	0 °	15 °	0 °	15 °
N	0.020	0.040	0.51	1.01

P SUFFIX
PLASTIC DIP PACKAGE
CASE 648–08
ISSUE R

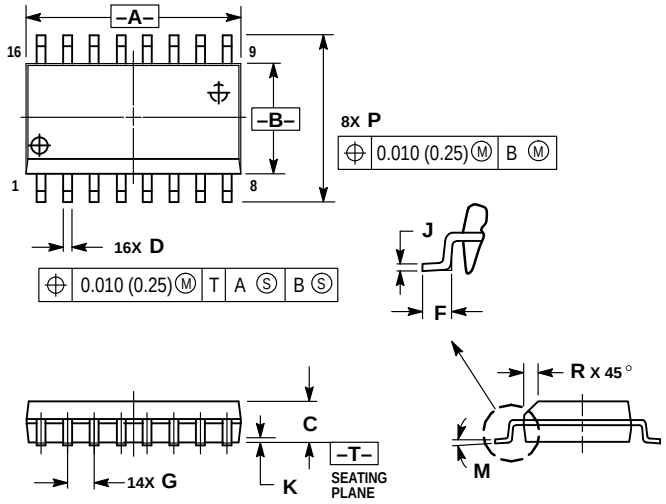


NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.
4. DIMENSION B DOES NOT INCLUDE MOLD FLASH.
5. ROUNDED CORNERS OPTIONAL.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
A	0.740	0.770	18.80	19.55
B	0.250	0.270	6.35	6.85
C	0.145	0.175	3.69	4.44
D	0.015	0.021	0.39	0.53
F	0.040	0.70	1.02	1.77
G	0.100 BSC		2.54 BSC	
H	0.050 BSC		1.27 BSC	
J	0.008	0.015	0.21	0.38
K	0.110	0.130	2.80	3.30
L	0.295	0.305	7.50	7.74
M	0 °	10 °	0 °	10 °
S	0.020	0.040	0.51	1.01

OUTLINE DIMENSIONS

DW SUFFIX
PLASTIC SOIC PACKAGE
CASE 751G–02
ISSUE A



NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.13 (0.005) TOTAL IN EXCESS OF D DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
A	10.15	10.45	0.400	0.411
B	7.40	7.60	0.292	0.299
C	2.35	2.65	0.093	0.104
D	0.35	0.49	0.014	0.019
F	0.50	0.90	0.020	0.035
G	1.27 BSC		0.050 BSC	
J	0.25	0.32	0.010	0.012
K	0.10	0.25	0.004	0.009
M	0 °	7 °	0 °	7 °
P	10.05	10.55	0.395	0.415
R	0.25	0.75	0.010	0.029

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